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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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## Renesas

# MOS FIELD EFFECT TRANSISTOR NP88N04NUG

### SWITCHING N-CHANNEL POWER MOSFET

#### DESCRIPTION

The NP88N04NUG is N-channel MOS Field Effect Transistor designed for high current switching applications.

#### FEATURES

- Channel temperature 175 degree rating
- Super low on-state resistance  $R_{DS(on)} = 3.4 \ m\Omega \ MAX. \ (V_{GS} = 10 \ V, \ I_D = 44 \ A)$
- Low Ciss: Ciss = 9510 pF TYP. (VDs = 25 V)

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

| Drain to Source Voltage (Vgs = 0 V)                                | VDSS            | 40                   | V  |
|--|-----------------|----------------------|----|
| Gate to Source Voltage (VDS = 0 V)                                 | Vgss            | ±20                  | V  |
| Drain Current (DC) (Tc = 25°C)                                     | D(DC)           | ±88                  | А  |
| Drain Current (pulse) <sup>Note1</sup>                             | D(pulse)        | ±352                 | А  |
| Total Power Dissipation  | P <sub>T1</sub> | 1.8                  | W  |
| Total Power Dissipation (Tc = $25^{\circ}$ C)                      | Pt2             | 200                  | W  |
| Channel Temperature  | Tch             | 175                  | °C |
| Storage Temperature  | Tstg            | –55 to +175          | °C |
| Repetitive Avalanche Current Note2                                 | IAR             | 56                   | А  |
| Repetitive Avalanche Energy Note2                                  | Ear             | 314                  | mJ |
| <b>Notes 1.</b> PW $\leq$ 10 $\mu$ s, Duty Cycle $\leq$ 1%         |                 |                      |    |
| <b>2.</b> $T_{ch} \le 150^{\circ}C$ , $V_{DD} = 20 V$ , $R_G = 25$ | 5 Ω, Vgs = 2    | $20 \rightarrow 0 V$ |    |

#### THERMAL RESISTANCE

| Channel to Case Thermal Resistance    | Rth(ch-C) | 0.75 | °C/W |
|---------------------------------------|-----------|------|------|
| Channel to Ambient Thermal Resistance | Rth(ch-A) | 83.3 | °C/W |

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#### ORDERING INFORMATION

| PART NUMBER | PACKAGE |
|-------------|---------|
| NP88N04NUG  | TO-262  |



(TO-262)

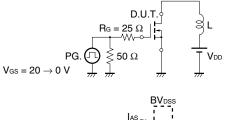
ELECTRICAL CHARACTERISTICS (TA = 25°C)

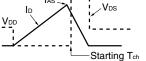
| CHARACTERISTICS                          | SYMBOL          | TEST CONDITIONS   | MIN. | TYP. | MAX.  | UNIT |
|--|-----------------|---|------|------|-------|------|
| Zero Gate Voltage Drain Current          | IDSS            | V <sub>DS</sub> = 40 V, V <sub>GS</sub> = 0 V               |      |      | 1     | μA   |
| Gate Leakage Current                     | lgss            | V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V              |      |      | ±100  | nA   |
| Gate to Source Threshold Voltage         | VGS(th)         | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA | 2.0  | 3.0  | 4.0   | V    |
| Forward Transfer Admittance Note         | y <sub>fs</sub> | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 44 A               | 27   | 51   |       | S    |
| Drain to Source On-state Resistance Note | RDS(on)         | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 44 A               |      | 2.6  | 3.4   | mΩ   |
| Input Capacitance                        | Ciss            | V <sub>DS</sub> = 25 V                                      |      | 9510 | 15000 | pF   |
| Output Capacitance                       | Coss            | V <sub>GS</sub> = 0 V                                       |      | 880  | 1370  | pF   |
| Reverse Transfer Capacitance             | Crss            | f = 1 MHz   |      | 570  | 990   | pF   |
| Turn-on Delay Time                       | td(on)          | V <sub>DD</sub> = 20 V, I <sub>D</sub> = 44 A               |      | 43   | 100   | ns   |
| Rise Time                                | tr              | V <sub>GS</sub> = 10 V                                      |      | 104  | 260   | ns   |
| Turn-off Delay Time                      | td(off)         | R <sub>G</sub> = 0 Ω  |      | 107  | 220   | ns   |
| Fall Time                                | tr              |   |      | 22   | 60    | ns   |
| Total Gate Charge                        | QG              | V <sub>DD</sub> = 32 V                                      |      | 171  | 250   | nC   |
| Gate to Source Charge                    | Q <sub>GS</sub> | V <sub>GS</sub> = 10 V                                      |      | 38   |       | nC   |
| Gate to Drain Charge                     | Qgd             | ID = 88 A   |      | 58   |       | nC   |
| Body Diode Forward Voltage Note          | VF(S-D)         | IF = 88 A, VGS = 0 V  |      | 0.94 | 1.5   | V    |
| Reverse Recovery Time                    | trr             | IF = 88 A, VGS = 0 V  |      | 51   |       | ns   |
| Reverse Recovery Charge                  | Qrr             | di/dt = 100 A/ <i>µ</i> s                                   |      | 67   |       | nC   |

Note Pulsed

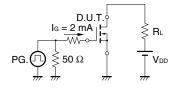
#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

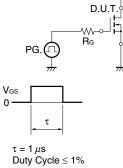
#### **TEST CIRCUIT 2 SWITCHING TIME**

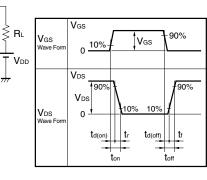




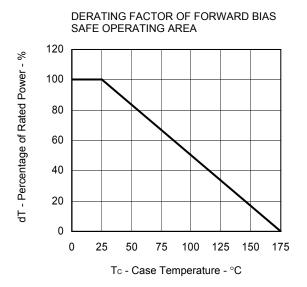
#### TEST CIRCUIT 3 GATE CHARGE



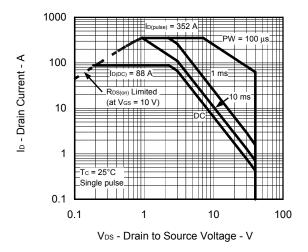


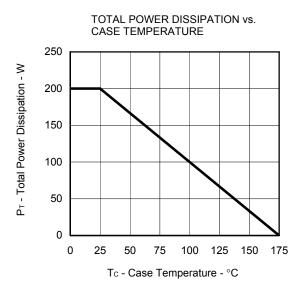


#### TYPICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )



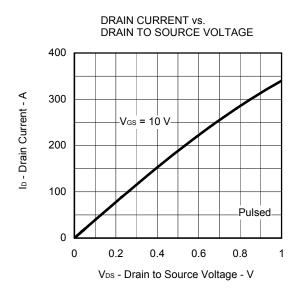




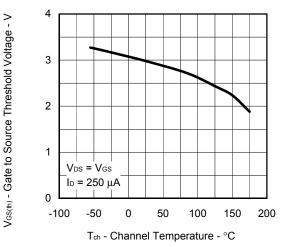


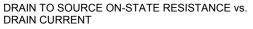
100  $r_{th(t)}$  - Transient Thermal Resistance -  $^{\circ}\text{C/W}$ Rth(ch-A) = 83.3°C/W 10 1 Rth(ch-C) = 0.75°C/W 0.1 Single pulse 0.01 1000  $100 \mu$ 1 m 10 m 100 m 10 100 1 PW - Pulse Width - s

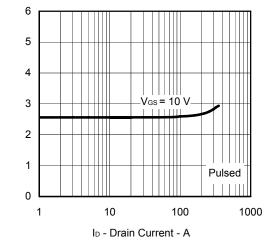
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



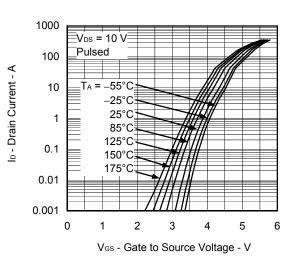




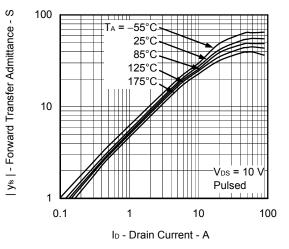




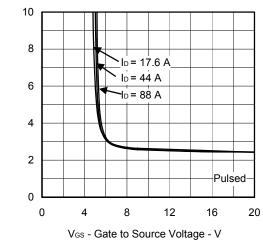
FORWARD TRANSFER CHARACTERISTICS



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



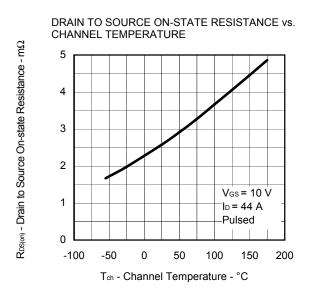
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



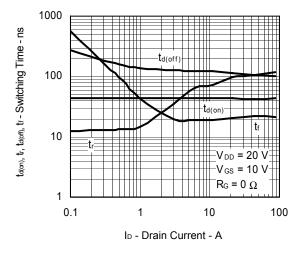


 $R_{DS(m)}$  - Drain to Source On-state Resistance - m $\Omega$ 

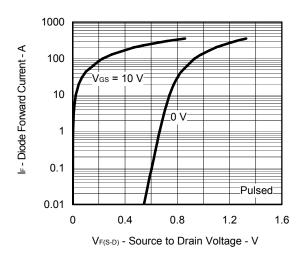
 $R_{DS(m)}$  - Drain to Source On-state Resistance - m $\Omega$ 



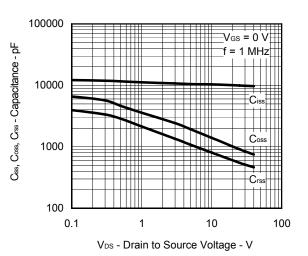
SWITCHING CHARACTERISTICS

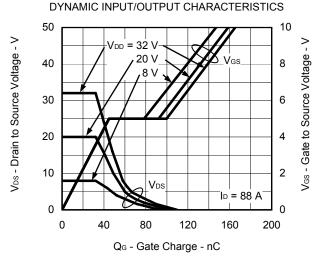


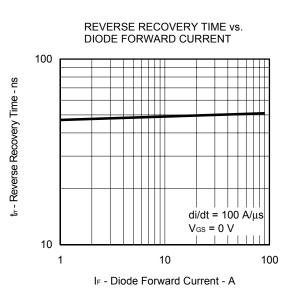
SOURCE TO DRAIN DIODE FORWARD VOLTAGE



CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

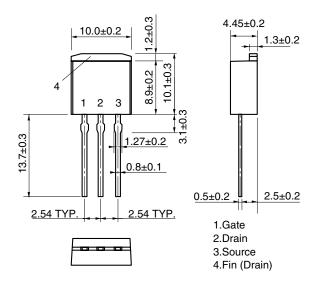




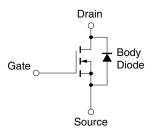


#### PACKAGE DRAWING (Unit: mm)

#### TO-262 (Revised)



EQUIVALENT CIRCUIT



**Remark** Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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